

# 2MBI200XBE120-50

IGBT Modules

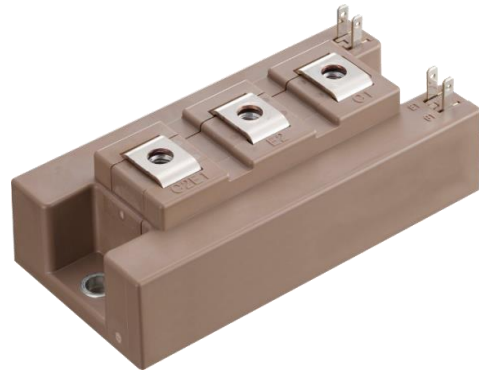
**Power Module (X series)**  
**1200V / 200A / 2-in-1 package**

■ **Features**

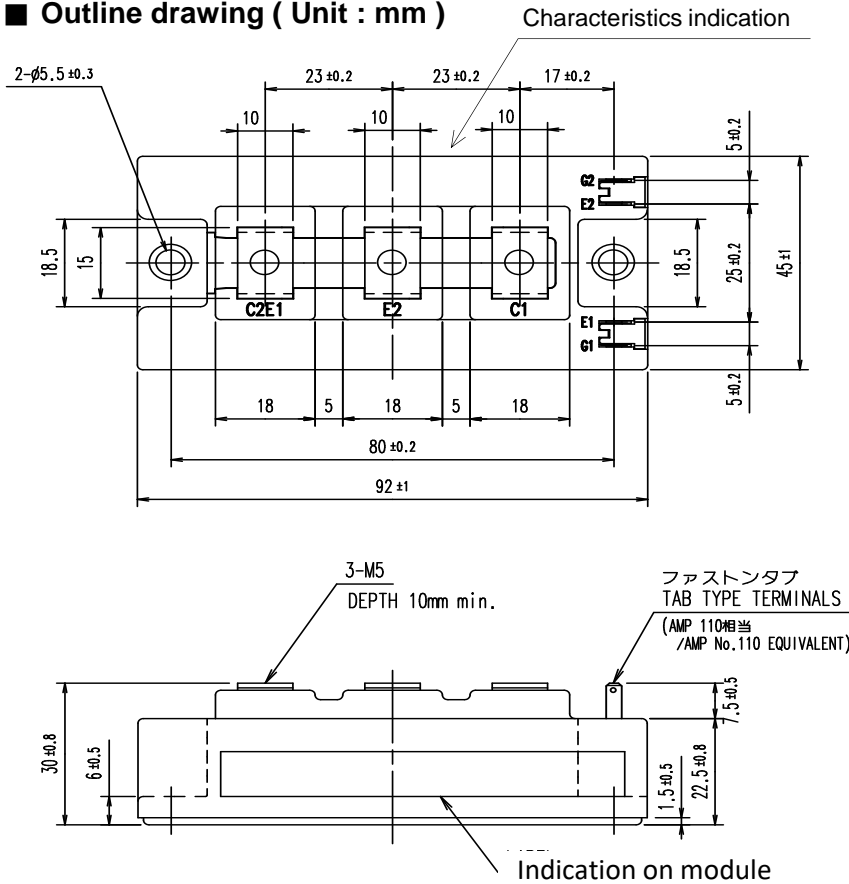
- LOW  $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines

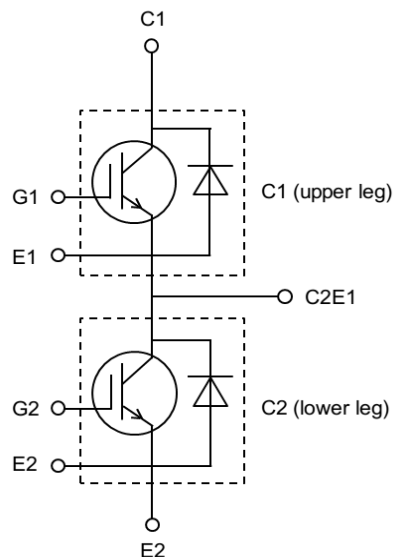


■ **Outline drawing ( Unit : mm )**



Weight: 240 g(typ.)

■ **Equivalent Circuit**





# 2MBI200XBE120-50

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**■ Electrical characteristics (at  $T_{vj}=25^{\circ}\text{C}$  unless otherwise specified)**

Items	Symbols	Conditions	Characteristics			Units			
			min.	typ.	max.				
Collector-Emitter cut-off current, Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$	-	-	100	$\mu\text{A}$			
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0\text{V}, V_{GE}=\pm 20\text{V}$	-	-	200	nA			
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20\text{V}$ $I_C = 200\text{mA}$	6.0	6.5	7.0	V			
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15\text{V}$ $I_C = 200\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.55	2.00	V		
	$V_{CE(sat)}$ (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.40	1.85			
			$T_{vj}=125^{\circ}\text{C}$	-	1.75	-			
			$T_{vj}=150^{\circ}\text{C}$	-	1.80	-			
Internal gate resistance	$r_g$	-	$T_{vj}=25^{\circ}\text{C}$	-	2.80	-	$\Omega$		
			Capacitance	$V_{CE}=10\text{V}, V_{GE}=0\text{V}, f=1\text{MHz}$	$C_{ies}$	-	23	-	nF
					$C_{oes}$	-	0.8	-	
					$C_{res}$	-	0.21	-	
Gate charge	$Q_G$	$V_{CC} = 600\text{V}, I_C = 200\text{A}$ $V_{GE} = -15 \rightarrow +15\text{V}$	-	1.5	-	$\mu\text{C}$			
Forward voltage	$V_F$ (terminal)	$V_{GE} = 0\text{V}$ $I_F = 200\text{A}$	$T_{vj}=25^{\circ}\text{C}$	-	1.75	2.20	V		
	$V_F$ (chip)		$T_{vj}=25^{\circ}\text{C}$	-	1.60	2.05			
			$T_{vj}=125^{\circ}\text{C}$	-	1.65	-			
			$T_{vj}=150^{\circ}\text{C}$	-	1.60	-			
Turn-on delay time(*1)	$t_{d(on)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 200\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 2.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.32	-	$\mu\text{s}$		
			$T_{vj}=125^{\circ}\text{C}$	-	0.35	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.36	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.37	-			
Rise time(*1)	$t_r$	$V_{CC} = 600\text{V}$ $I_C, I_F = 200\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 2.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.06	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.07	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.07	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.08	-			
Turn-off delay time(*1)	$t_{d(off)}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 200\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 2.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.36	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.40	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.42	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.43	-			
Fall time(*1)	$t_f$	$V_{CC} = 600\text{V}$ $I_C, I_F = 200\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 2.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.13	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.21	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.23	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.25	-			
Reverse recovery time	$t_{rr}$	$V_{CC} = 600\text{V}$ $I_C, I_F = 200\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 2.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.28	-			
			$T_{vj}=125^{\circ}\text{C}$	-	0.49	-			
			$T_{vj}=150^{\circ}\text{C}$	-	0.55	-			
			$T_{vj}=175^{\circ}\text{C}$	-	0.60	-			

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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■ Electrical characteristics (at  $T_{vj}=25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	max.			
Inverter	Turn-on energy	$V_{CC} = 600\text{V}$ $I_C, I_F = 200\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 2.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	19.0	-	mJ	
			$T_{vj}=125^{\circ}\text{C}$	-	26.4	-		
			$T_{vj}=150^{\circ}\text{C}$	-	28.3	-		
			$T_{vj}=175^{\circ}\text{C}$	-	30.1	-		
	Turn-off energy		$E_{off}$	$T_{vj}=25^{\circ}\text{C}$	-	17.7		-
				$T_{vj}=125^{\circ}\text{C}$	-	20.7		-
				$T_{vj}=150^{\circ}\text{C}$	-	21.5		-
				$T_{vj}=175^{\circ}\text{C}$	-	22.2		-
	Reverse recovery energy		$E_{rr}$	$T_{vj}=25^{\circ}\text{C}$	-	7.8		-
				$T_{vj}=125^{\circ}\text{C}$	-	12.7		-
				$T_{vj}=150^{\circ}\text{C}$	-	13.9		-
				$T_{vj}=175^{\circ}\text{C}$	-	15.2		-

NOTICE:

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

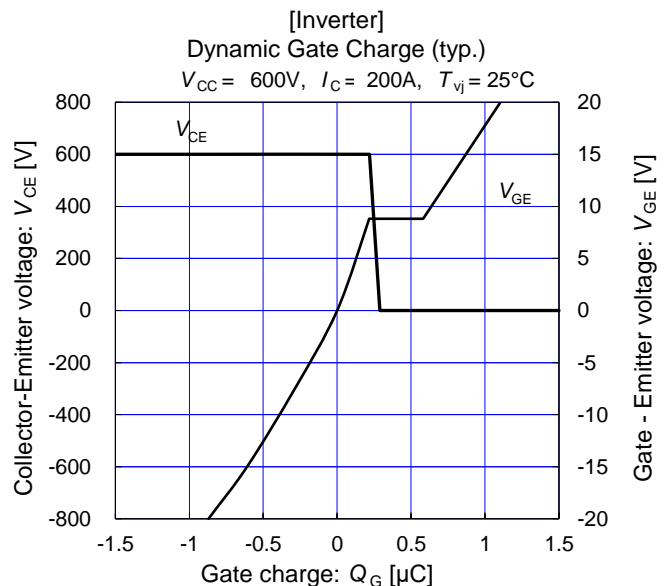
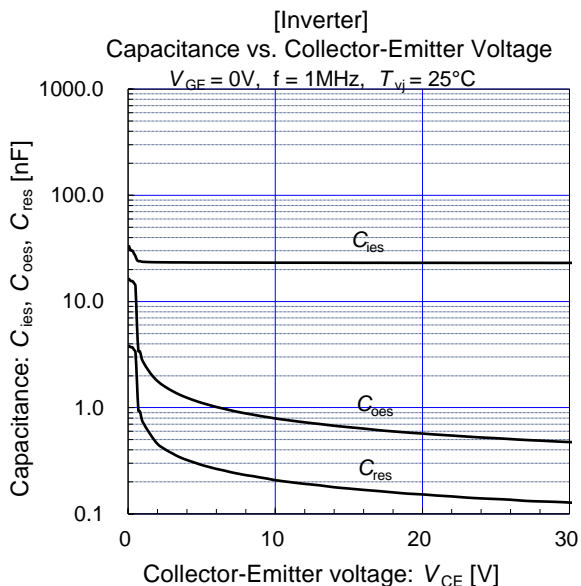
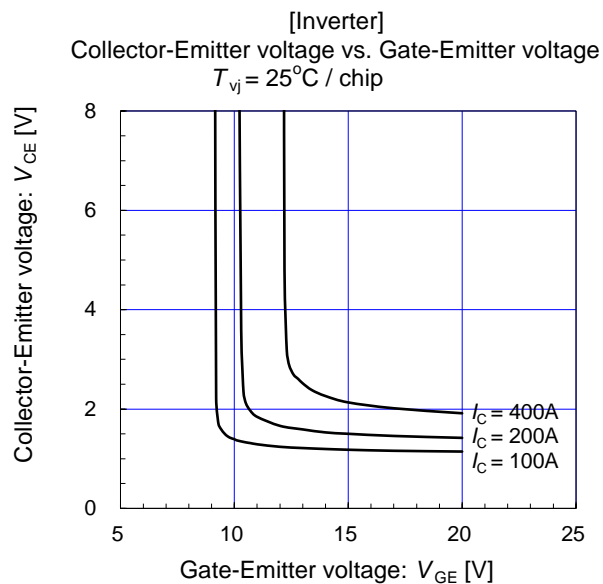
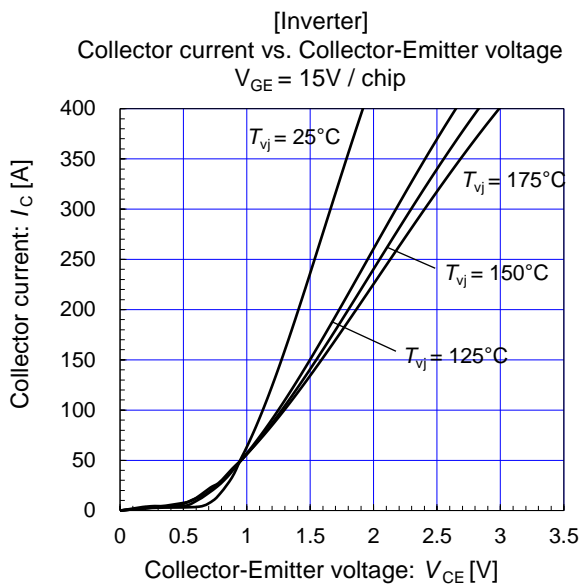
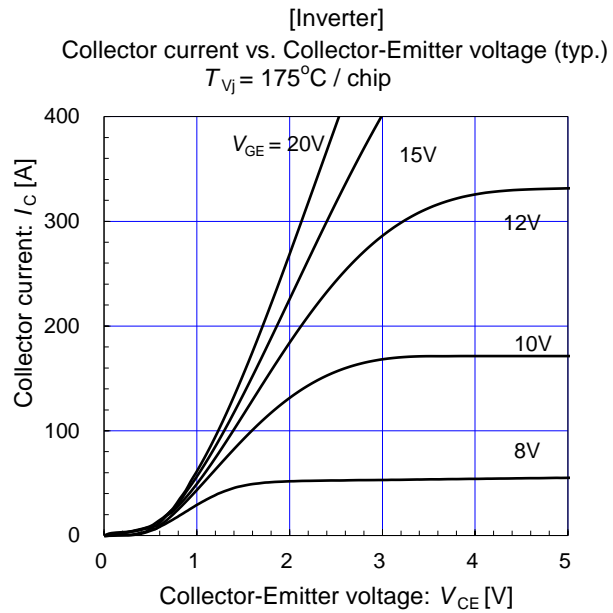
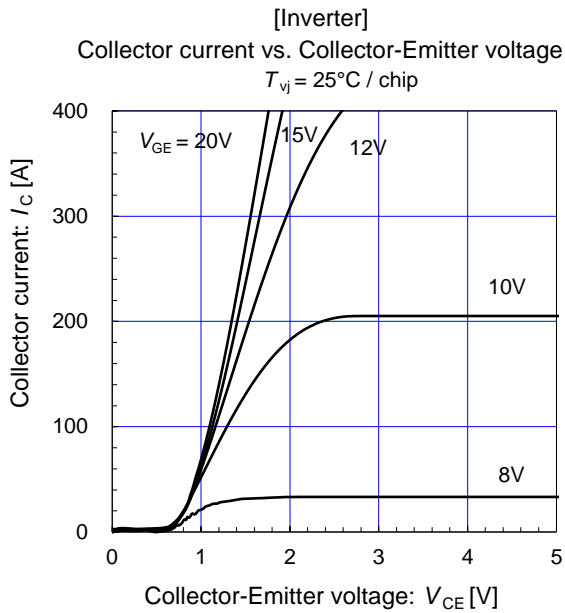
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.101	$^{\circ}\text{C/W}$
		Inverter FWD	-	-	0.169	
Thermal resistance case to heat sink (1 IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.025	-	

(\*1) This is the value which is defined mounting on the additional heat sink with thermal grease.

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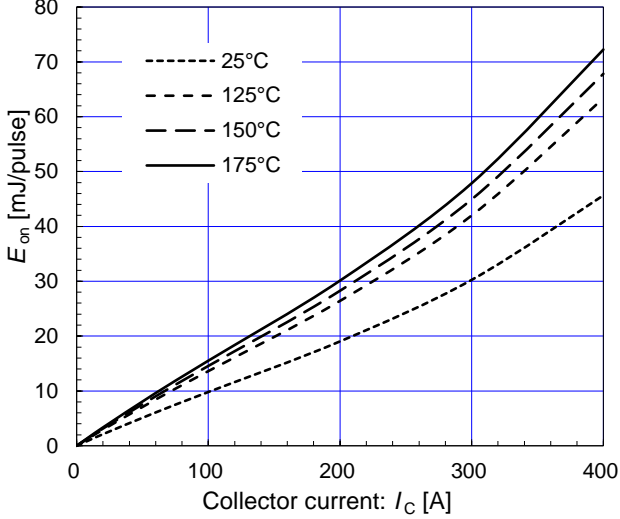
# 2MBI200XBE120-50

IGBT Modules

[Inverter]

$E_{on}$  vs. Collector current (typ.)

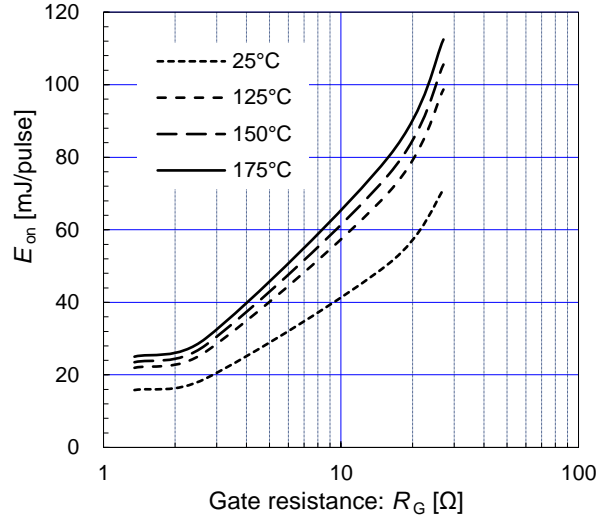
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 2.7 \Omega$



[Inverter]

$E_{on}$  vs. Gate resistance (typ.)

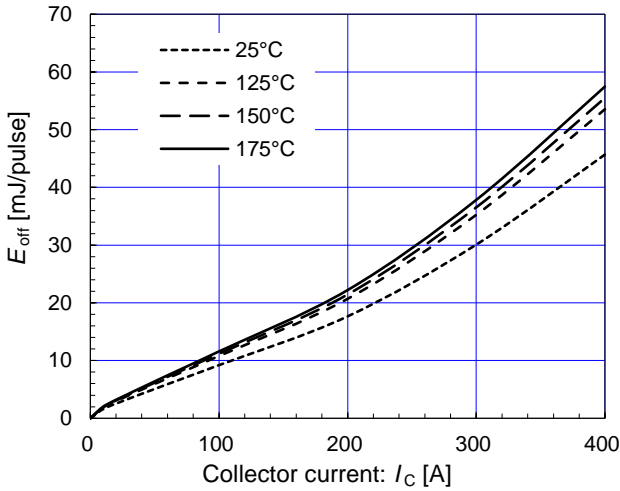
$V_{CC} = 600V, V_{GE} = +15/-15V, I_C = 200A$



[Inverter]

$E_{off}$  vs. Collector current (typ.)

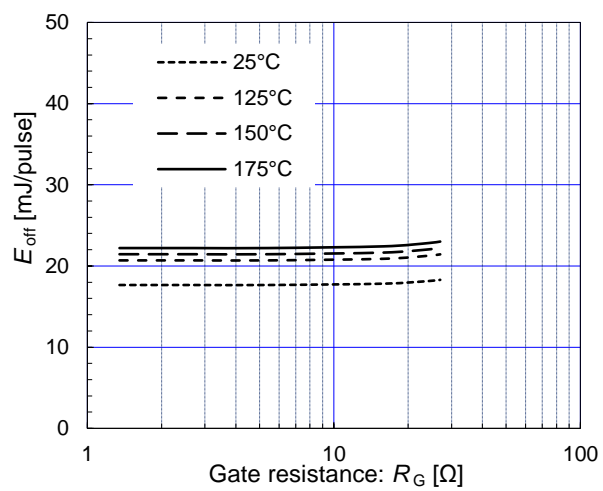
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 2.7 \Omega$



[Inverter]

$E_{off}$  vs. Gate resistance (typ.)

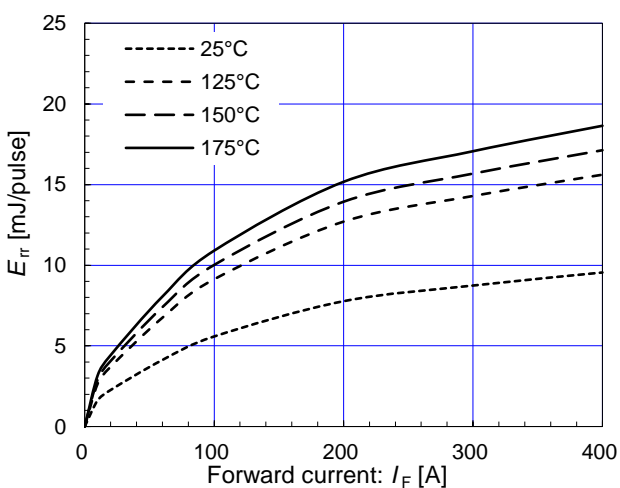
$V_{CC} = 600V, V_{GE} = +15/-15V, I_C = 200A$



[Inverter]

$E_{rr}$  vs. Forward current (typ.)

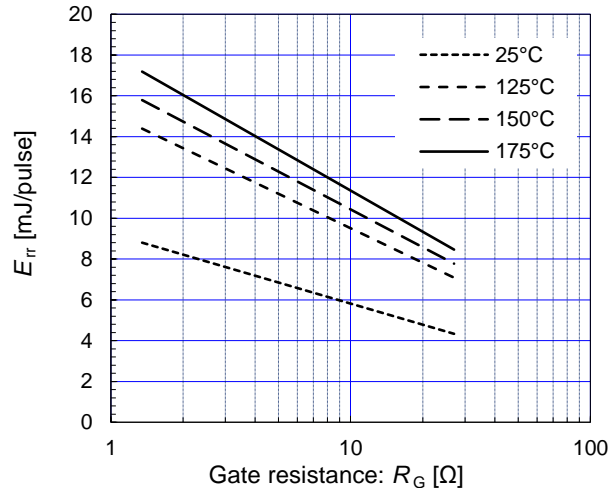
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 2.7 \Omega$



[Inverter]

$E_{rr}$  vs. Gate resistance (typ.)

$V_{CC} = 600V, V_{GE} = +15/-15V, I_F = 200A$

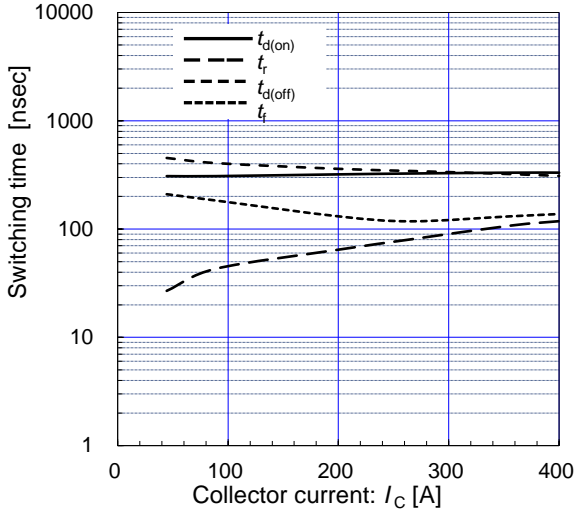


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[Inverter]

Switching time vs. Collector current (typ.)

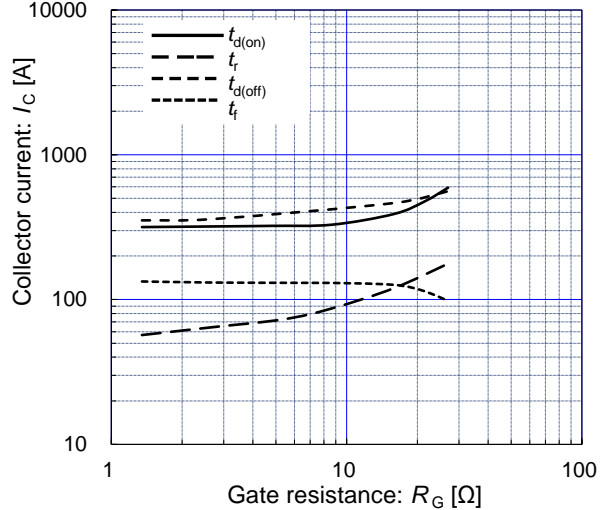
$V_{CC} = 600V, R_G = 2.7\Omega, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

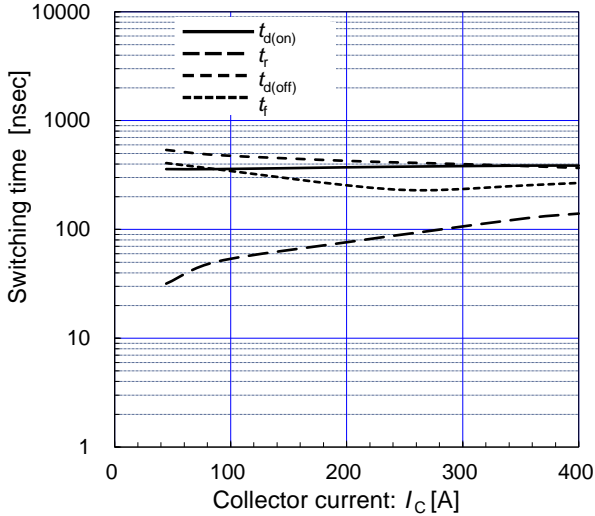
$V_{CC} = 600V, I_C = 200A, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Collector current (typ.)

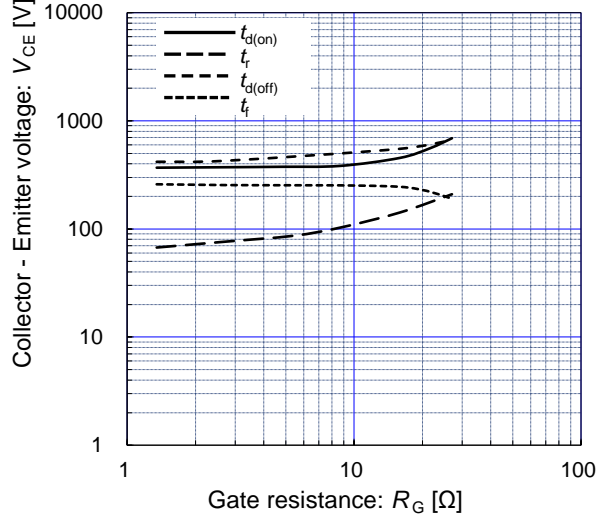
$V_{CC} = 600V, R_G = 2.7\Omega, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

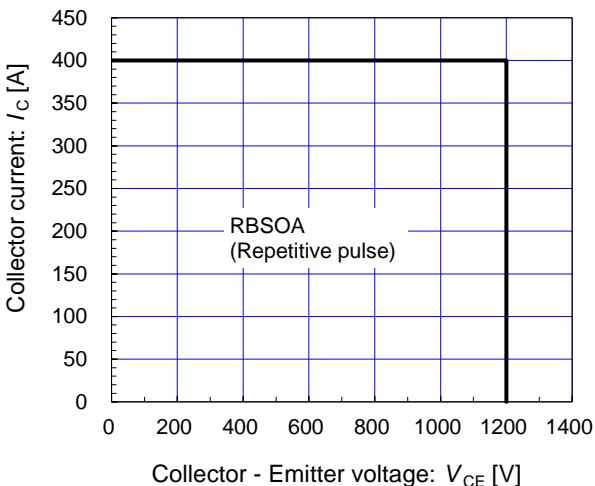
$V_{CC} = 600V, I_C = 200A, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

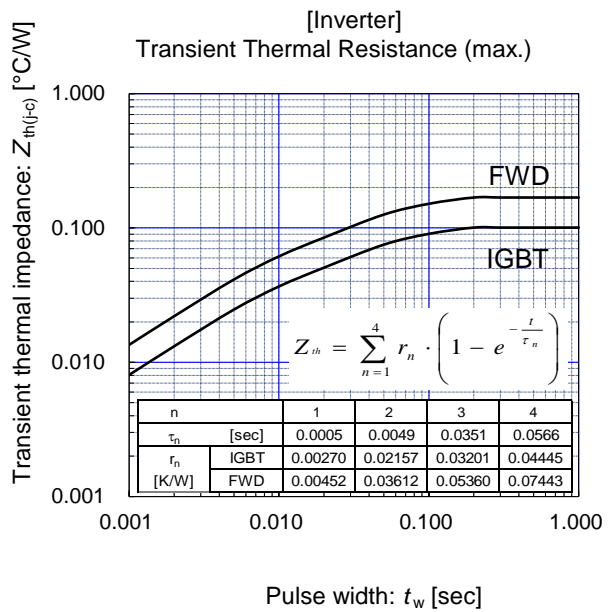
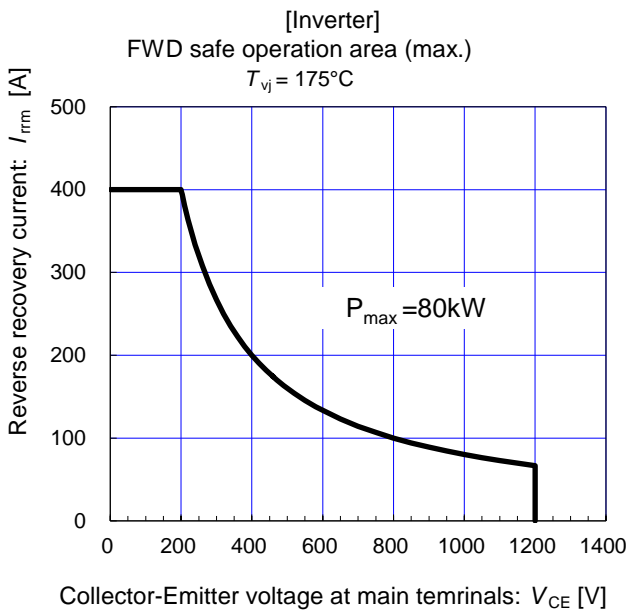
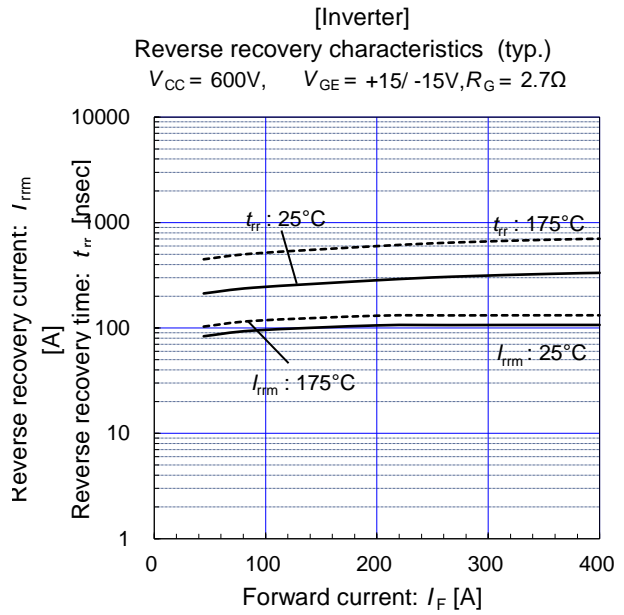
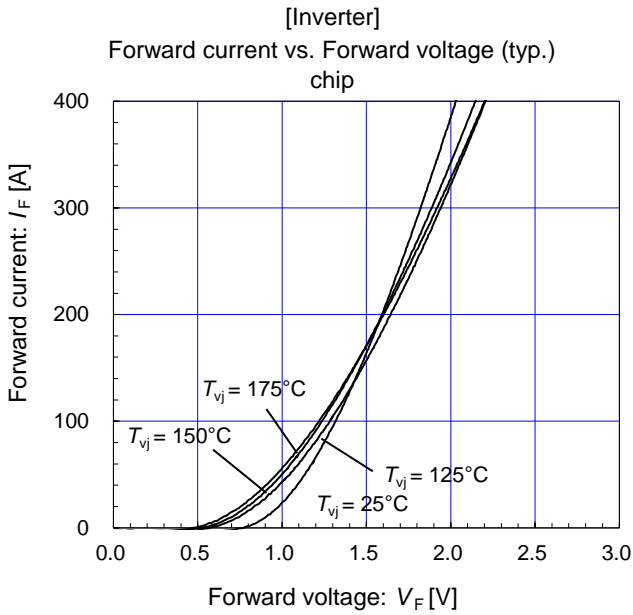
Reverse bias safe operating area (max.)

$V_{GE} = +15/-15, R_G = 2.7\Omega, T_{vj} = 175^\circ C$



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IGBT Modules





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## IGBT Modules

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